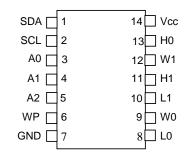


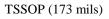
DS1855 integrated Dual Nonvolatile Digital Potentiometer and Secure Memory

FEATURES

- Two Linear Taper Potentiometers
 - DS1855-010 (One $10k\Omega$, 100 Position and One $10k\Omega$, 256 Position)
 - DS1855-020 (One $10k\Omega$, 100 Position and One $20k\Omega$, 256 Position)
 - DS1855-050 (One $10k\Omega$, 100 Position and One 50k Ω , 256 Position)
 - DS1855-100 (One $10k\Omega$, 100 Position and One 100k Ω , 256 Position)
- 256 Bytes of EEPROM Memory
- Access to Data and Potentiometer Control via a 2-Wire Interface
- External Write-Protect Pin to Protect Data and Potentiometer Settings
- Data and Potentiometer Settings Also Can Be Write Protected Through Software Control
- Nonvolatile Wiper Storage
- . Operates from 3V or 5V Supplies
- 14-Pin TSSOP, 16-Ball CSBGA, and 14-Pin Flip-Chip Packages
- **Industrial Operating Temperature:** -40°C to +85°C

PIN CONFIGURATIONS







A	\bigcirc	\bigcirc	\bigcirc	\bigcirc
В	\bigcirc	\bigcirc	\bigcirc	\bigcirc
С	\bigcirc	\bigcirc	\bigcirc	\bigcirc
D	\bigcirc	()	()	\bigcirc
	1	2	3	4

CSBGA (4mm x 4mm) Flip Chip (100 mils x 100 mils) (Not Shown)

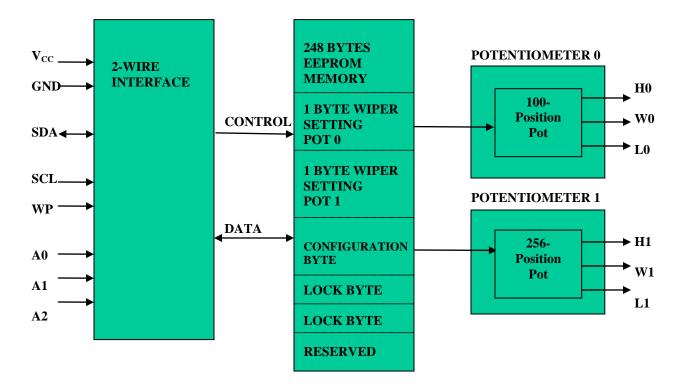
DESCRIPTION

The DS1855 dual nonvolatile (NV) digital potentiometer and secure memory consists of one 100-position linear taper potentiometer, one 256-position linear taper potentiometer, 256 bytes of EEPROM memory, and a 2-wire interface. The DS1855, which features a new software write protect, is an upgrade of the DS1845. The DS1855 provides an ideal method for setting bias voltages and currents in control applications using a minimum of circuitry. The EEPROM memory allows a user to store configuration or calibration data for a specific system or device as well as provide control of the potentiometer wiper settings. Any type of user information may reside in the first 248 bytes of this memory. The next two addresses of EEPROM memory are for potentiometer settings and the remaining 6 bytes of memory are reserved. These reserved and potentiometer registers should not be used for data storage. Access to this EEPROM is via an industry-standard 2-wire bus. The interface I/O pins consist of SDA and SCL. The wiper position of the DS1855, as well as EEPROM data, can be write protected through hardware using the write-protect input pin (WP) or software using the 2-wire interface.

PIN DESCRIPTIONS

<u>Name</u>	TSSOP	BGA	Description
V _{CC}	14	A3	Power Supply Terminal. The DS1855 will support supply
			voltages ranging from +2.7V to +5.5V.
GND	7	D1	Ground Terminal.
SDA	1	B2	2-Wire serial data interface. The serial data pin is for serial data
			transfer to and from the DS1855. The pin is open drain and may
			be wire-ORed with other open drain or open collector interfaces.
SCL	2	A2	2-Wire Serial Clock Input. The serial clock input is used to
			clock data into the DS1855 on rising edges and clock data out on
		~ 4	falling edges.
WP	6	C1	Write Protect Input. If set to logic 0, the data in memory and the
			potentiometer wiper setting may be changed. If set to logic 1, both
			the memory and the potentiometer wiper settings will be write
4.0	2	A 1	protected. The WP pin is pulled high internally.
A0	3	A1	Address Input. Pins A0, A1, and A2 are used to specify the address of each DS1855 when used in a multi-dropped
			configuration. Up to eight DS1855 may be addressed on a single
			2-wire bus.
A1	4	B1	Address Input.
A1 A2	5	C2	Address Input.
HO	13	A4	High terminal of Potentiometer 0. For both potentiometers, it is
110	10		not required that the high terminal be connected to a potential
			greater than the low terminal. Voltage applied to the high terminal
			of each potentiometer cannot exceed V_{CC} or go below ground.
H1	11	B3	High terminal of Potentiometer 1.
LO	8	D3	Low terminal of Potentiometer 0. For both potentiometers, it is
			not required that the low terminal be connected to a potential less
			than the high terminal. Voltage applied to the low terminal of each
			potentiometer cannot exceed V_{CC} or go below ground.
L1	10	C4	Low terminal of Potentiometer 1.
W0	9	D4	Wiper terminal of Pot 0. The wiper position of Potentiometer 0
			is determined by the byte at EEPROM memory location F9h.
			Voltage applied to the wiper terminal of each potentiometer cannot
1171	10	D4	exceed the power supply voltage, V_{CC} , or go below ground.
W1	12	B4	Wiper terminal of Pot 1. The wiper position of Potentiometer 1 is determined by the byte at EEPROM memory location F8h.
NC		C3	No Connect.
NC NC		D2	No Connect.
		D_{-}	

DS1855 BLOCK DIAGRAM Figure 1



Up to eight DS1855s can be installed on a single 2-wire bus. Access to an individual device is achieved by using a device address that is determined by the logic levels of address pins A0 through A2. Additionally, the DS1855 will operate from 3V or 5V supplies. Three package options are available: 14-pin TSSOP, 16-ball CSBGA, and a flip-chip package.

MEMORY ORGANIZATION

The DS1855's serial EEPROM is internally organized with 256 words of 1 byte each. Each word requires an 8-bit address for random word addressing. The byte at address F9h determines the wiper setting for potentiometer 0, which contains 100 positions. Writing values above 63h to this address sets the wiper to its uppermost position, but the MSB is ignored. The byte at address F8h determines the wiper setting for potentiometer 1, which contains 256 positions (00h to FFh). Address locations FAh though FFh are reserved and should not be written.

MEMORY LOCATION	NAME OF MEMORY LOCATION	FUNCTION OF MEMORY LOCATION
00h – F7h	User Memory	General-purpose user memory.
F8h	Potentiometer 1 Setting	Writing to this byte controls the setting of potentiometer 1, a 256- position pot. Valid settings are 00h to FFh.
F9h	Potentiometer 0 Setting	Writing to this byte controls the setting of potentiometer 0, a 100- position pot. Valid settings are 00h to 63h. MSB is ignored.
FAh	Software Lock Configuration Byte	The three lower bits in this byte can be used to set write-protection to the 256-byte memory block. B2 B1 B0 B2 : Writing this bit to a 1 protects the upper page of memory. If this bit is set, memory locations F8h to FFh are configured for write-protection. B1 : Writing this bit to a 1 protects the upper block of memory. If this bit is set, memory locations 80h to F7h are configured for write-protection. The upper page must be unlocked in order to modify the locking of this portion of memory. B0 : Writing this bit to a 1 protects the lower block of memory. If this bit is set, memory locations 00h to 7Fh are configured for write-protection. The upper page must be unlocked in order to modify the locking of this portion of memory.

FBh – FCh	Lock Bytes	Writing to these two bytes allows the user to lock or unlock the memory described in byte FAh.LOCK: If memory location FBh is written to 56h and memory location FCh is written to 25h, the device will enter lock mode.
		Write protection will become active in the memory locations that are specified in FAh.
		UNLOCK: If memory location FBh is written to 67h and memory location FCh is written to 36h, the device will be unlocked. Once unlocked, the user can change the setting of memory location FAh to affect the EEPROM write-protection.
		The locking can be updated at any time as long as the upper page is unlocked.
FD – FFh	Reserved	Reserved

2-WIRE OPERATION

Clock and Data Transitions

The SDA pin is normally pulled high with an external resistor or device. Data on the SDA pin may only change during SCL low time periods. Data changes during SCL high periods will indicate a START or STOP conditions depending on the conditions discussed below. Refer to the timing diagram in Figure 2 for further details.

START Condition

A high-to-low transition of SDA with SCL high is a START condition that must precede any other command. Refer to the timing diagram in Figure 2 for further details.

STOP Condition

A low-to-high transition of SDA with SCL high is a STOP condition. After a read sequence, the stop command places the DS1855 into a low-power mode. Refer to the timing diagram in Figure 2 for further details.

Acknowledge

All address and data bytes are transmitted via a serial protocol. The DS1855 pulls the SDA line low during the ninth clock pulse to acknowledge that it has received each word.

Standby Mode

The DS1855 features a low-power mode that is automatically enabled after power-on, after a STOP command, and after the completion of all internal operations.

2-Wire Interface Reset

After any interruption in protocol, power loss, or system reset, the following steps reset the DS1855:

- 1. Clock up to nine cycles.
- 2. Look for SDA high in each cycle while SCL is high.
- 3. Create a START condition while SDA is high.

Device Addressing

The DS1855 must receive an 8-bit device address word following a START condition to enable a specific device for a read or write operation. The address word is clocked into the DS1855 MSB to LSB. The address word consists of Ah (1010) followed by A2, A1, and A0 then the read/write (R/W) bit. If the R/W bit is high, a read operation is initiated. If the R/W is low, a write operation is initiated. For a device to become active, the values of A2, A1, and A0 must be the same as the hard-wired address pins on the DS1855. Upon a match of written and hard-wired addresses, the DS1855 will output a zero for one clock cycle as an acknowledge. If the address does not match, the DS1855 returns to a low-power mode.

Write Operations

After receiving a matching address byte with the R/W bit set low, the device goes into the write mode of operation. The master must transmit an 8-bit EEPROM memory address to the device to define the address where the data is to be written. After the reception of this byte, the DS1855 will transmit a zero for one clock cycle to acknowledge the receipt of the address. The master must then transmit an 8-bit data word to be written into this address. The DS1855 will again transmit a zero for one clock cycle to acknowledge the receipt of the master must terminate the write operation with a STOP condition. The DS1855 then enters an internally timed write process T_w to the EEPROM memory. All inputs are disabled during this byte write cycle.

The DS1855 is capable of an 8-byte page write. A page write is initiated the same way as a byte write, but the master does not send a STOP condition after the first byte. Instead, after the slave acknowledges receipt of the data byte, the master can send up to seven more bytes using the same nine-clock sequence. The master must terminate the write cycle with a STOP condition or the data clocked into the DS1855 will not be latched into permanent memory.

Acknowledge Polling

Once the internally timed write has started and the DS1855 inputs are disabled, acknowledge polling can be initiated. The process involves transmitting a START condition followed by the device address. The R/W bit signifies the type of operation that is desired. The read or write sequence will only be allowed to proceed if the internal write cycle has completed and the DS1855 responds with a zero.

Read Operations

After receiving a matching address byte with the R/W bit set high, the device goes into the read mode of operation. There are three read operations: current address read, random read, and sequential address read.

CURRENT ADDRESS READ

The DS1855 has an internal address register that maintains the address used during the last read or write operation, incremented by one. This data is maintained as long as V_{CC} is valid. If the most recent address was the last byte in memory, the register resets to the first address. This address stays valid between operations as long as power is available.

Once the device address is clocked in and acknowledged by the DS1855 with the R/W bit set to high, the current address data word is clocked out. The master does not respond with a zero, but does generate a STOP condition afterwards.

RANDOM READ

A random read requires a dummy-byte write sequence to load in the data word address. Once the device and data address bytes are clocked in by the master and acknowledged by the DS1855, the master must generate another START condition. The master now initiates a current address read by sending the device address with the read/write bit set high. The DS1855 acknowledges the device address and serially clocks out the data byte.

SEQUENTIAL ADDRESS READ

Sequential reads are initiated by either a current address read or a random address read. After the master receives the first data byte, the master responds with an acknowledge. As long as the DS1855 receives this acknowledge after a byte is read, the master may clock out additional data words from the DS1855. After reaching address FFh, it resets to address 00h.

The sequential read operation is terminated when the master initiates a STOP condition. The master does not respond with a zero.

For a more detailed description of 2-wire theory of operation, refer to the next section.

2-WIRE SERIAL PORT OPERATION

The 2-wire serial port interface supports a bidirectional data transmission protocol with device addressing. A device that sends data on the bus is defined as a transmitter, and a device receiving data is defined as a receiver. The device that controls the message is called a "master." The devices that are controlled by the master are "slaves." The bus must be controlled by a master device that generates the serial clock (SCL), controls the bus access, and generates the START and STOP conditions. The DS1855 operates as a slave on the two-wire bus. Connections to the bus are made via the open-drain I/O lines, SDA and SCL. The following I/O terminals control the 2-wire serial port: SDA, SCL, A0, A1, A2. Timing diagrams for the 2-wire serial port can be found in Figures 2 and 3. Timing information for the 2-wire serial port is provided in the AC Electrical Characteristics table for 2-wire serial communications.

The following bus protocol has been defined:

- 1. Data transfer may be initiated only when the bus is not busy.
- 2. During data transfer, the data line must remain stable whenever the clock line is HIGH. Changes in the data line while the clock line is HIGH will be interpreted as control signals.

Accordingly, the following bus conditions have been defined:

Bus not busy: Both data and clock lines remain HIGH.

Start data transfer: A change in the state of the data line from HIGH to LOW while the clock is HIGH defines a START condition.

Stop data transfer: A change in the state of the data line from LOW to HIGH while the clock line is HIGH defines the STOP condition.

Data valid: The state of the data line represents valid data when, after a START condition, the data line is stable for the duration of the clock signal's HIGH period. The data on the line can be changed during the clock signal's LOW period. There is one clock pulse per bit of data. Figures 2 and 3 detail how data transfer is accomplished on the 2-wire bus. Depending on the state of the R/W bit, two types of data transfer are possible.

Each data transfer is initiated with a START condition and terminated with a STOP condition. The number of data bytes transferred between START and STOP conditions is not limited and is determined by the master device. The information is transferred byte-wise and each receiver acknowledges with a 9th bit.

A regular mode (100kHz clock rate) and a fast mode (400kHz clock rate) are defined within the bus specifications. The DS1855 works in both modes.

Acknowledge: Each receiving device, when addressed, is obliged to generate an acknowledge after the reception of each byte. The master device must generate an extra clock pulse, which is associated with this acknowledge bit.

A device that acknowledges must pull down the SDA line during the acknowledge clock pulse in such a way that the SDA line is a stable LOW during the HIGH period of the acknowledge-related clock pulse. Of course, setup and hold times must be taken into account. A master must signal an end of data to the

slave by not generating an acknowledge bit on the last byte that has been clocked out of the slave. In this case, the slave must leave the data line HIGH to enable the master to generate the STOP condition.

- 1. Data transfer from a master transmitter to a slave receiver. The first byte transmitted by the master is the command/control byte. Next, follows a number of data bytes. The slave returns an acknowledge bit after each received byte.
- 2. Data transfer from a slave transmitter to a master receiver. The master transmits the first byte (the command/control byte) to the slave. The slave then returns an acknowledge bit. Next, follows a number of data bytes transmitted by the slave to the master. The master returns an acknowledge bit after all received bytes other than the last byte. At the end of the last received byte, a 'not acknowledge' can be returned.

The master device generates all serial clock pulses and the START and STOP conditions. A transfer is ended with a STOP condition or with a repeated START condition. Since a repeated START condition is also the beginning of the next serial transfer, the bus will not be released.

The DS1855 may operate in the following two modes:

- 1. **Slave receiver mode:** Serial data and clock are received through SDA and SCL, respectively. After each byte is received, an acknowledge bit is transmitted. START and STOP conditions are recognized as the beginning and end of a serial transfer. Address recognition is performed by hardware after reception of the slave (device) address and direction bit.
- 2. **Slave transmitter mode:** The first byte is received and handled as in the slave receiver mode. However, in this mode the direction bit will indicate that the transfer direction is reversed. Serial data is transmitted on SDA by the DS1855 while the serial clock is input on SCL. START and STOP conditions are recognized as the beginning and end of a serial transfer.
- 3. Slave Address: Command/control byte is the first byte received following the START condition from the master device. The command/control byte consists of a 4-bit control code. For the DS1855, this is set as *1010* binary for read/write operations. The next 3 bits of the command/control byte are the device select bits or slave address (A2, A1, A0). They are used by the master device to select which of eight devices is to be accessed. When reading or writing to the DS1855, the device-select bits must match the device-select pins (A2, A1, A0). The last bit of the command/control byte (R/W) defines the operation to be performed. When set to a 1 a read operation is selected, and when set to a 0 a write operation is selected.

Following the START condition, the DS1855 monitors the SDA bus by checking the device type identifier being transmitted. Upon receiving the 1010 control code, the appropriate device address bits, and the R/W bit, the slave device outputs an acknowledge signal on the SDA line.

WRITE PROTECT

An external write-protect (WP) pin protects EEPROM data and potentiometer position from alteration in an application. If this pin is open or tied high, the EEPROM content, which includes the potentiometer settings, is protected from alteration. If no activity occurs on the SDA and SCL pins, this part will be held in a low-power mode. The EEPROM and potentiometer settings may be read if WP is set, but they cannot be written under any circumstances unless WP is taken to GND.

LOCKING AND UNLOCKING EEPROM

In addition to the WP pin, it is possible to write-protect, or lock, certain portions of the EEPROM through software control. The DS1855 256-byte EEPROM can be visualized as three blocks, or partitions. The lower block is from 00h to 7Fh. The upper block is 80h to F7h. And the upper page is from F8 to FFh. The lower and upper blocks are user EEPROM. The upper page is EEPROM that contains the pot settings, as well as the lock registers.

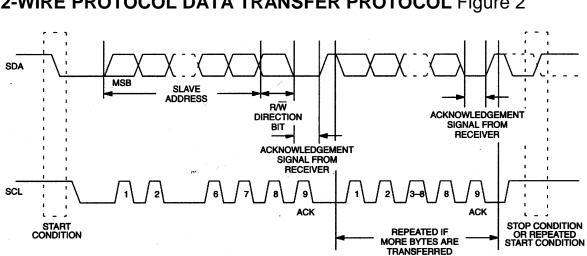
Locking the EEPROM is a two-step process. First, the software lock configuration byte (FAh) is used to choose which portion(s) of EEPROM are to be locked. The three least significant bits of FAh are B2, B1, and B0. B2 selects the upper page (F8–FFh). B1 selects the upper block (80–F7h). The LSBit, B0, selects the lower block (00–7Fh). The user may lock one, two, or all three partitions at once. The second step required to turn on the lock is to write the password into the lock bytes (FBh and FCh). The password to lock is 56h, 25h (FBh and FCh, respectively). Once the EEPROM is locked, the user may still read data out of the locked portions, but performing a write will not write to EEPROM.

Unlocking the EEPROM consists of entering the password into bytes FBh and FCh. The password to unlock is 67h, 36h (FBh and FCh, respectively). However, when attempting to unlock the upper page, which contains the lock bytes (FBh and FCh), the two-byte password must be written in one write cycle. If a 2-wire STOP command is sent between the write to FBh and FCh, the upper page will remain locked.

In order to modify the Software Lock Configuration Byte (FAh), the upper page must be unlocked. In other words, the upper page must be unlocked in order to make changes to the locking of the upper and lower blocks.

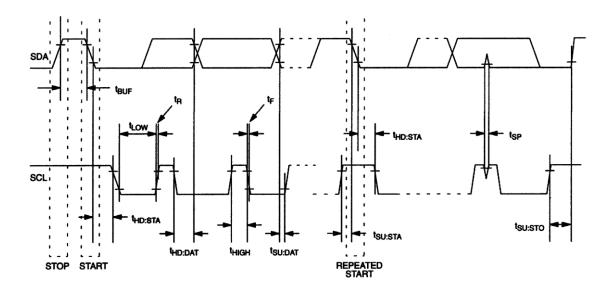
READING AND WRITING THE POTENTIOMETER VALUES

Reading from and writing to the potentiometers consists of a standard read or write to EEPROM memory at the addresses F8h and F9h. The 8-bit value at address F9h controls the wiper setting for potentiometer 0, which has 100 positions. The 8-bit value at address F8h controls the wiper setting of potentiometer 1, which has 256 positions. Potentiometer 1 may be set to any value between 00h and FFh. 00h sets the wiper of potentiometer 1 to its lowest value and FFh sets the wiper to its highest. Potentiometer 0 may be set to any value between 00h and 63h. A value of 00h sets the wiper of potentiometer 0 to its lowest position and 63h sets the wiper to its highest position. Any hexadecimal value is a valid address. Setting a value greater than the upper limit of the potentiometer's range, 64h or greater for potentiometer 0, will result in setting the wiper to its highest position, but the MSB will be ignored. The memory locations F8h and F9h, which control the potentiometers' settings, are programmed to FFh when shipped from the factory. All other memory locations are initially programmed to 00h.



2-WIRE PROTOCOL DATA TRANSFER PROTOCOL Figure 2

2-WIRE AC CHARACTERISTICS Figure 3



ABSOLUTE MAXIMUM RATINGS

Voltage Range on Any Pin Relative to Ground	-0.3V to +6.0V
Operating Temperature Range -40° C to $+85^{\circ}$ C	
Programming Temperature Range	0° C to $+85^{\circ}$ C
Storage Temperature Range	-55°C to +125°C
Lead Temperature (TSSOP only: soldering, 10s)	+300°C
Soldering Temperature (reflow)	
TSSOP or CSBGA, Lead(Pb)-free	+260°C
TSSOP or CSBGA, Containing Lead(Pb)	+240°C
Flip Chip	+240°C

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect device reliability.

Note: The DS1855 is built to the highest quality standards and manufactured for long-term reliability. All DS1855s are made using the same quality materials and manufacturing methods. However, the DS1855 in the flip-chip package is not exposed to environmental stresses, such as burn-in, that some industrial applications require. For specific reliability information on this product, contact the factory.

RECOMMENDED DC OPERATING CONDITIONS

 $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNITS	NOTES
Supply Voltage	V _{CC}		+2.7		5.5	V	1

DC ELECTRICAL CHARACTERISTICS

($V_{CC} = 2.7V$ to 5.5V; $T_A = -40^{\circ}C$ to +85°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNITS	NOTES
Active Supply Current	I _{CC}				0.5	mA	11, 12
Input Leakage	I _{LI}		-1		+1	μΑ	
Input Logic 1	V _{IH}		0.7 x V _{CC}		V _{CC} + 0.3	v	
Input Logic 0	V _{IL}		V _{GND} - 0.3		0.3 x V _{CC}	v	
Input Current Each I/O Pin		$\begin{array}{l} 0.4 < V_{I\!/O,} \\ < 0.9 \ x \ V_{DD} \end{array}$	-10		+10	μΑ	3
	т	3.0V		20	40		2
Standby Current	I _{STBY}	5.0V		30	60	μA	2
Low-Level Output	V _{OL1}	3mA sink current	0.0		0.4	v	
Voltage (SDA)	V _{OL2}	6mA sink current	0.0		0.6	v	
I/O Capacitance	C _{I/O}				10	pF	
WP Internal Pullup Resistance	R _{WP}		40	65	100	kΩ	

ANALOG RESISTOR CHARACTERISTICS

(V_{CC} = 2.7V to 5.5V; $T_A = -40^{\circ}C$ to +85°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNITS	NOTES
Resistor Inputs	L, H, W		V _{GND} - 0.3		V _{CC} + 0.3	V	
Winer Desistance	R _W	3.0V		400	1000		
Wiper Resistance		5.0V		250	600	Ω	
Wiper Current	Iw				2	mA	
End-to-End Resistance		$T_A = +25^{\circ}C$	-20		+20	%	
		10kΩ/100 pos	-0.75		+0.75	LSB	9
		10kΩ/256 pos	-0.75		+0.75		
Absolute Linearity		20kΩ/256 pos	-1.0		+1.0		
		50kΩ/256 pos	-1.5		+1.5		
		100kΩ/256 pos	-2.25		+2.25		
Relative Linearity		10kΩ/100 pos	-0.25		+0.25	LSB	10
Relative Linearity		All other pots	-0.5		+0.5	LSD	10
-3dB Cutoff Frequency	f _{CUTOFF}	DS1855-010		1		MHz	
End-to-End Temp. Coefficient				750		ppm/°C	

AC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
CCL Clash Engrund	c	Fast Mode	0		400	1.11.	4
SCL Clock Frequency	f_{SCL}	Standard Mode	0		100	kHz	
Bus Free Time Between	t	Fast Mode	1.3				4
STOP and START	t _{BUF}	Standard Mode	4.7			μs	4
Hold Time (Repeated)	t	Fast Mode	0.6				4, 5
START Condition	t _{HD:STA}	Standard Mode	4.0			μs	4, 5
Low Period of SCL	t	Fast Mode	1.3				4
Clock	t _{LOW}	Standard Mode	4.7			μs	4
High Period of SCL	t	Fast Mode	0.6				4
Clock	t _{HIGH}	Standard Mode	4.0			μs	4
Data Hold Time	t _{HD:DAT}	Fast Mode	0		0.9	μs	4, 6
Data Holu Tille		Standard Mode	0		0.9		
Data Setup Time	t _{SU:DAT}	Fast Mode	100			ns	4
Data Setup Time		Standard Mode	250				
Start Satur Time	t	Fast Mode	0.6				4
Start Setup Time	t _{SU:STA}	Standard Mode	4.7			μs	4
Rise Time of Both SDA	t	Fast Mode	20+0.1C _B		300	na	4
and SCL Signals	t _R	Standard Mode	20+0.1C _B		1000	ns	4
Fall Time of Both SDA	t	Fast Mode	20+0.1C _B		300	na	7
and SCL Signals	t _F	Standard Mode	20+0.1C _B		300	ns	1
Setup Time for STOP	t	Fast Mode	0.6				
Condition	t _{SU:STO}	Standard Mode	4.0			μs	
Capacitive Load for	C _B				400	pF	7
Each Bus Line EEPROM Write Time	t _W			2.5	10	ms	8

NONVOLATILE MEMORY CHARACTERISTICS

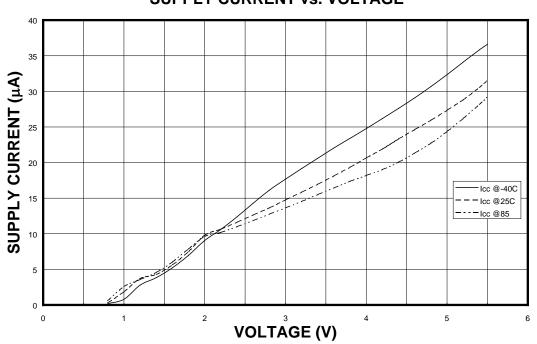
PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNITS	NOTES
Writes		$T_A = +85^{\circ}C$	50,000				

NOTES:

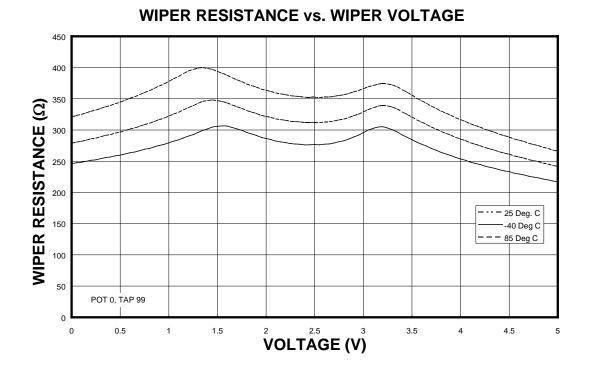
- 1. All voltages are referenced to ground.
- 2. I_{STBY} specified with for $V_{CC} = 3.0V$ and 5.0V, and control port logic pins are driven to the appropriate logic levels. Appropriate logic levels specify that logic inputs are within a 0.5V of ground or V_{CC} for the corresponding inactive state.
- 3. I/O pins of fast mode devices must not obstruct the SDA and SCL lines if V_{CC} is switched off.
- 4. A fast mode device can be used in a standard mode system, but the requirement $t_{SU:DAT} > 250$ ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{RMAX} + t_{SU:DAT} = 1000 + 250 = 1250$ ns before the SCL line is released.
- 5. After this period, the first clock pulse is generated.
- 6. The maximum t_{HD:DAT} has only to be met if the device does not stretch the LOW period (t_{LOW}) of the SCL signal.
- 7. C_B Total capacitance of one bus line in picofarads, timing referenced to 0.9 x V_{CC} and 0.1 x V_{CC}.
- 8. EEPROM write begins after a STOP condition occurs.
- 9. Absolute linearity is used to measure expected wiper voltage as determined by wiper position.
- 10. Relative linearity is used to determine the change of wiper voltage between two adjacent wiper positions.
- 11. I_{CC} specified with SDA pin open.
- 12. Maximum I_{CC} is dependent on clock rates.

TYPICAL OPERATING CHARACTERISTICS

(V_{CC} = 5V, T_A = +25°C, unless otherwise noted.)

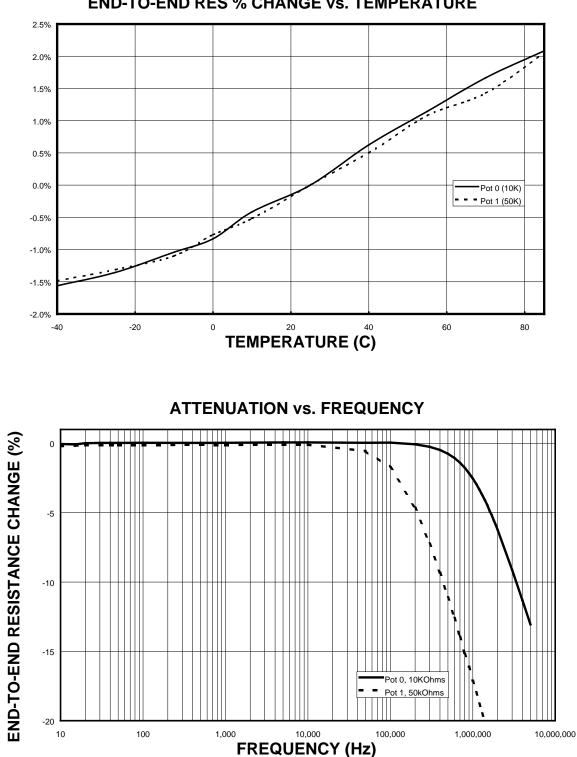


SUPPLY CURRENT vs. VOLTAGE



TYPICAL OPERATING CHARACTERISTICS (cont.)

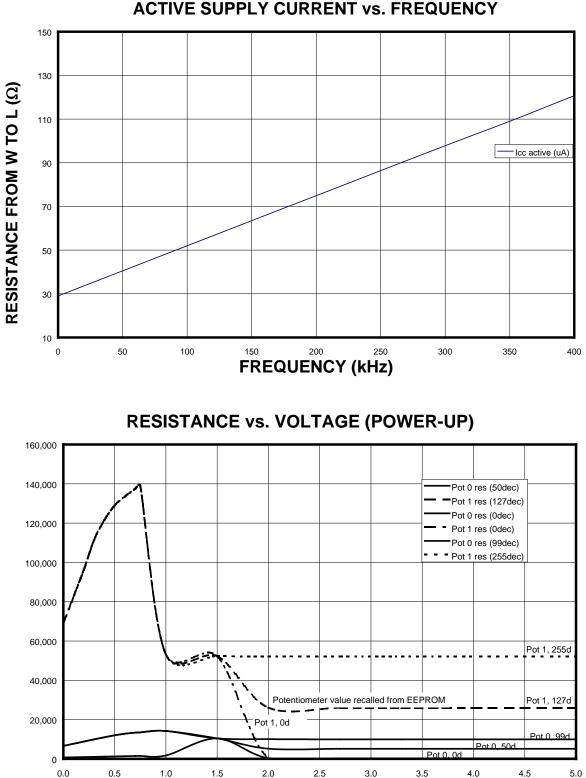
 $(V_{CC} = 5V, T_A = +25^{\circ}C, unless otherwise noted.)$



END-TO-END RES % CHANGE vs. TEMPERATURE

TYPICAL OPERATING CHARACTERISTICS (cont.)

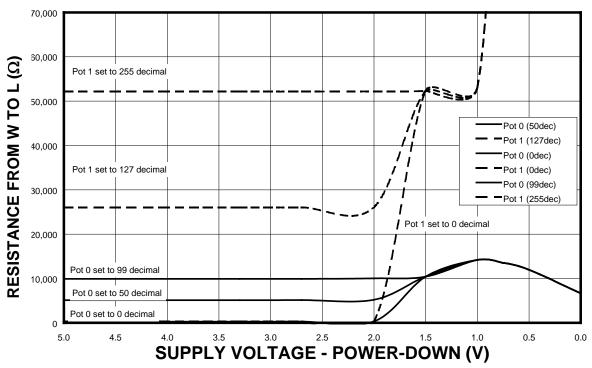
 $(V_{CC} = 5V, T_A = +25^{\circ}C, unless otherwise noted.)$



SUPPLY VOLTAGE - POWER-UP (V)

TYPICAL OPERATING CHARACTERISTICS (cont.)

($V_{CC} = 5V$, $T_A = +25^{\circ}C$, unless otherwise noted.)



RESISTANCE vs. VOLTAGE (POWER-DOWN)

ORDERING INFORMATION

PART	TEMP RANGE	VERSION Pot 0/Pot 1	PIN-PACKAGE
DS1855B-010	-40°C to +85°C	10kΩ/10kΩ	16 CSBGA
DS1855B-010/T&R	-40°C to +85°C	10kΩ/10kΩ	16 CSBGA
DS1855B-010+	-40°C to +85°C	10kΩ/10kΩ	16 CSBGA
DS1855B-010+T&R	-40°C to +85°C	10kΩ/10kΩ	16 CSBGA
DS1855B-020	-40°C to +85°C	$10k\Omega/20k\Omega$	16 CSBGA
DS1855B-050	-40°C to +85°C	10kΩ/50kΩ	16 CSBGA
DS1855B-050+	-40°C to +85°C	$10k\Omega/50k\Omega$	16 CSBGA
DS1855B-100	-40°C to +85°C	$10k\Omega/100k\Omega$	16 CSBGA
DS1855B-100+	-40°C to +85°C	$10k\Omega/100k\Omega$	16 CSBGA
DS1855E-010	-40°C to +85°C	10kΩ/10kΩ	14 TSSOP
DS1855E-010/T&R	-40°C to +85°C	10kΩ/10kΩ	14 TSSOP
DS1855E-010+	-40°C to +85°C	$10k\Omega/10k\Omega$	14 TSSOP
DS1855E-010+T&R	-40°C to +85°C	10kΩ/10kΩ	14 TSSOP
DS1855E-020	-40°C to +85°C	$10k\Omega/20k\Omega$	14 TSSOP
DS1855E-020/T&R	-40°C to +85°C	$10k\Omega/20k\Omega$	14 TSSOP/
DS1855E-050	-40°C to +85°C	$10k\Omega/50k\Omega$	14 TSSOP
DS1855E-050/T&R	-40°C to +85°C	10kΩ/50kΩ	14 TSSOP
DS1855E-050+	-40°C to +85°C	$10k\Omega/50k\Omega$	14 TSSOP
DS1855E-050+T&R	-40°C to +85°C	$10k\Omega/50k\Omega$	14 TSSOP
DS1855E-100	-40°C to +85°C	$10k\Omega/100k\Omega$	14 TSSOP
DS1855E-100/T&R	-40°C to +85°C	$10k\Omega/100k\Omega$	14 TSSOP
DS1855X-010	-40°C to +85°C	10kΩ/10kΩ	14 FLIP CHIP
DS1855X-020	-40°C to +85°C	10kΩ/20kΩ	14 FLIP CHIP
DS1855X-050/T&R	-40°C to +85°C	10kΩ/50kΩ	14 FLIP CHIP
DS1855X-100	-40°C to +85°C	$10k\Omega/100k\Omega$	14 FLIP CHIP

+Denotes a lead(Pb)-free/RoHS-compliant package. T&R = Tape and reel.

PACKAGE INFORMATION

For the latest package outline information and land patterns, go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 CSBGA	X16+1	<u>21-0355</u>	<u>90-0334</u>
14 TSSOP	U14+1	<u>21-0066</u>	<u>90-0113</u>
14 FLIP CHIP	BF1422-1	<u>21-0285</u>	—

REVISION HISTORY

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	1/13	Added the soldering information for all package variants to the <i>Absolute Maximum Ratings</i> section; updated the <i>Ordering Information</i> table and added the <i>Package Information</i> table	12, 20

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